UNISONIC TECHNOLOGIES CO., LTD

TIP112

NPN SILICON TRANSISTOR

NPN EPITAXIAL SILICON DARLINGTON TRANSISTOR

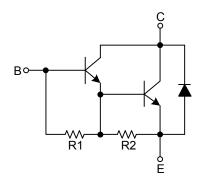
■ DESCRIPTION

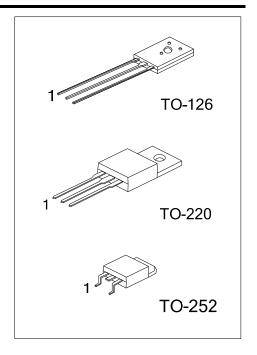
The UTC **TIP112** is designed for such applications as: DC/DC converters supply line switching, battery charger, LCD backlighting, peripheral drivers, Driver in low supply voltage applications (e.g. lamps and LEDs) and inductive load driver (e.g. relays, buzzers and motors).

■ FEATURES

- * High DC current gain : h_{FE} = 1000 @ V_{CE} =4V, I_{C} =1A (Min)
- * Low collector-emitter saturation voltage

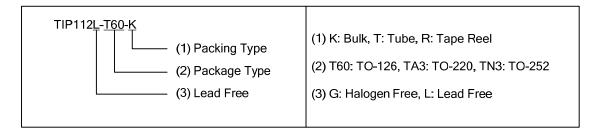
■ **EQUIVALENT TEST** ($R_1 \approx 10 k\Omega$, $R_2 \approx 0.6 k\Omega$)





■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
TIP112L-T60-K	TIP112G-T60-K	TO-126	Е	С	В	Bulk	
TIP112L-TA3-T	TIP112G-TA3-T	TO-220	В	С	Е	Tube	
TIP112L-TN3-R	TIP112G-TN3-R	TO-252	В	С	Е	Tape Reel	
TIP112L-TN3-T	TIP112G-TN3-T	TO-252	В	С	Е	Tube	



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■ ABSOLUTE MAXIMUM RATING (T_C =25°C, unless otherwise specified)

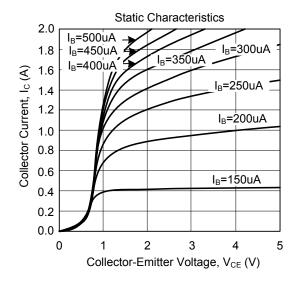
PARAMETER		SYMBOL	RATINGS	UNIT
Collector to Base Voltage		V_{CBO}	100	V
Collector to Emitter Voltage		V _{CEO}	100	V
Emitter to Base Voltage		V_{EBO}	5	V
Collector Current	DC	I _C	2	^
	Peak	I _{CM}	4	A
Base Current (DC)		I _B	50	mA
Collector Dissipation	TO-126		10	
	TO-220	Pc	40	W
	TO-252		15	
Junction Temperature	`	TJ	150	°C
Storage Temperature		T _{STG}	-65~+150	°C

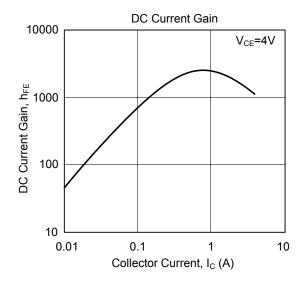
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

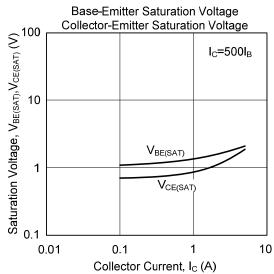
■ ELECTRICAL CHARACTERISTICS (T_C =25°C, unless otherwise specified)

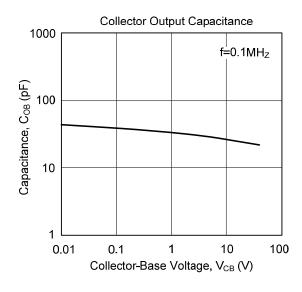
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	V _{CEO(SUS)}	I _C =30mA, I _B =0A	100			V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I _C =2A, I _B =8mA			2.5	V
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	V _{CE} =4V, I _C =2A			2.8	
Collector-Base Cut-Off Current	I _{CBO}	V _{CB} =100V, I _E =0A			1	mA
Collector-Emitter Cut-Off Current	I _{CEO}	V_{CE} =50V, V_{B} =0A			2	mA
Emitter-Base Cut-Off Current	I _{EBO}	V _{EB} =5V, I _C =0A			2	mA
DO Commont Onlin	h _{FE}	V _{CE} =4V, I _C =1A	1000			
DC Current Gain		V_{CE} =4 V , I_{C} =2 A	500			
Collector Capacitance	Сов	V _{CB} =10V, I _E =0A, f=0.1MHz			100	pF

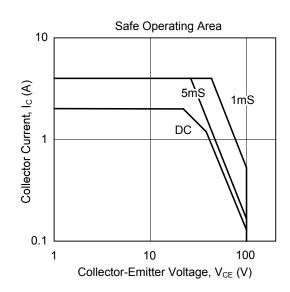
■ TYPICAL CHARACTERISTICS

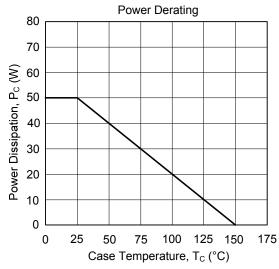












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